NSN 5962-01-386-7109

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Between 1.270 inches and 1.290 inches

Body Width:

Between 0.590 inches and 0.610 inches

Body Height:

Between 0.205 inches and 0.225 inches

Maximum Power Dissipation Rating:

950.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

An/fps-117

Features Provided:

Bipolar and burn in, mil-std-883, class b and electrostatic sensitive and high impedance and monolithic and programmed and schottky and tested to mil-std-883 and 3-state output and w/enable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

14 input

Criticality Code Justification:

Feat

Case Outline Source And Designator:

D-3 mil-m-38510

Current Rating Per Characteristic:

185.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, digital, read only memory

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source and -1.5 volts input and 5.5 volts input

Time Rating Per Chacteristic:

90.00 nanoseconds input to output access

Memory Device Type:

Prom

Special Features:

Altered item programmed using device m38510/20904bjx; esd

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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A458a0